

TOSHIBA DIODE SILICON EPITAXIAL PLANAR TYPE

1SV309

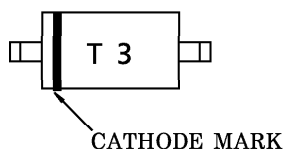
UHF SHF TUNING

- High Capacitance Ratio : $C_{2V}/C_{25V}=5.7$ (Typ.)
- Low Series Resistance : $r_s=1.2\Omega$ (Typ.)
- Excellent C-V Characteristics, and Small Tracking Error
- Useful for Small Size Tuner

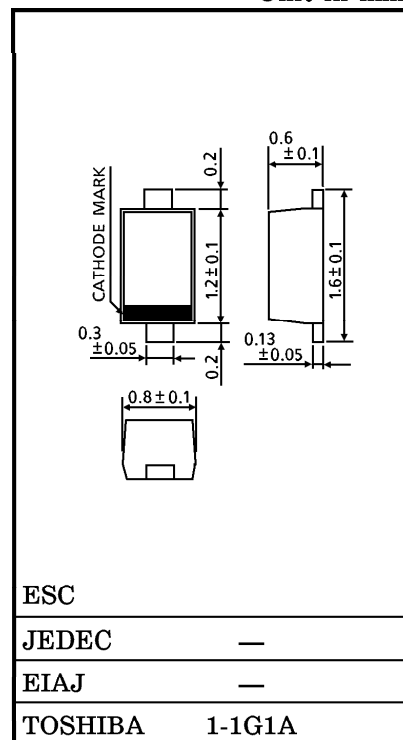
MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Reverse Voltage	V_R	30	V
Peak Reverse Voltage	V_{RM}	35 ($R_L=10k\Omega$)	V
Junction Temperature	T_j	125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55~125	$^\circ\text{C}$

MARKING



Unit in mm



ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

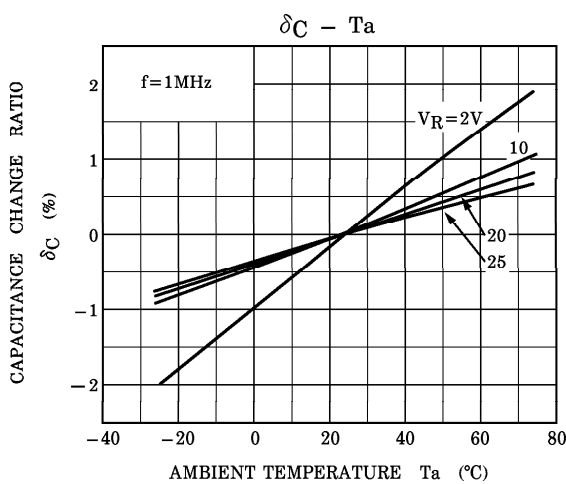
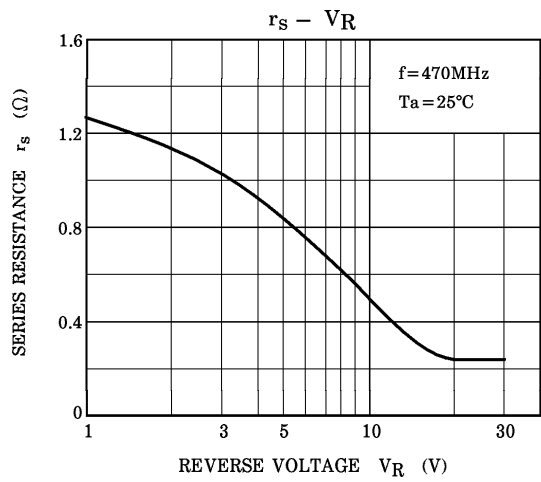
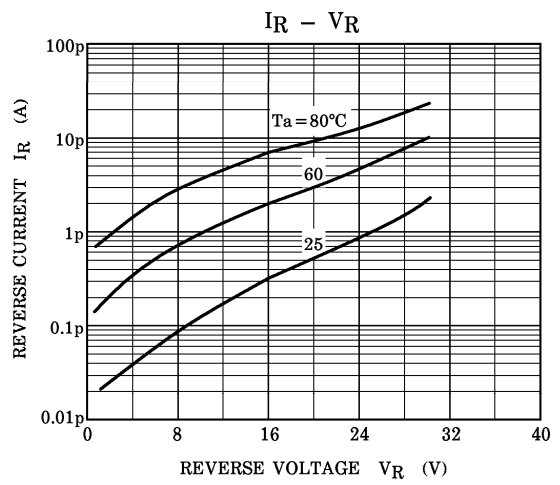
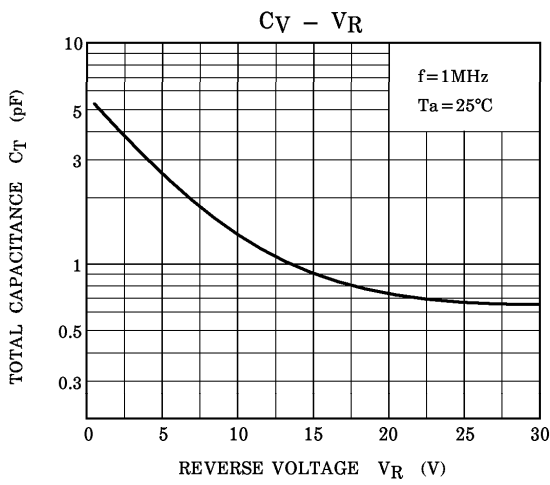
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Reverse Voltage	V_R	$I_R=1\mu\text{A}$	30	—	—	V
Reverse Current	I_R	$V_R=28\text{V}$	—	—	10	nA
Capacitance	C_{2V}	$V_R=2\text{V}, f=1\text{MHz}$	3.31	—	4.55	pF
Capacitance	C_{25V}	$V_R=25\text{V}, f=1\text{MHz}$	0.61	—	0.77	pF
Capacitance Ratio	C_{2V}/C_{25V}	—	5.0	—	6.5	—
Series Resistance	r_s	$V_R=1\text{V}, f=470\text{MHz}$	—	1.2	2.0	Ω

(Note) Unites are compounded in one package and are matched to 6.0%.

$$\frac{C(\text{Max.}) - C(\text{Min.})}{C(\text{Min.})} \leq 0.06$$

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NOTE : $\delta C (\%) = \frac{C(T_a = T^\circ C) - C(T_a = 25^\circ C)}{C(T_a = 25^\circ C)} \times 100$